

QUERY CONTROL FORM		RTIS USE ONLY	
Application No. <u>10/603621</u>	Prepared by <u>BYU</u>	Tracking Number <u>593.0567</u>	
Examiner-GAU <u>ISA1-2812</u>	Date <u>5/10/04</u>	Week Date <u>4/5/04</u>	
	No. of queries <u>1</u>	<u>IFW</u>	

JACKET			
a. Serial No.	f. Foreign Priority	k. Print Claim(s)	p. PTO-1449
b. Applicant(s)	g. Disclaimer	l. Print Fig.	q. PTOL-85b
c. Continuing Data	h. Microfiche Appendix	m. Searched Column	r. Abstract
d. PCT	i. Title	n. PTO-270/328	s. Sheets/Figs
e. Domestic Priority	j. Claims Allowed	o. PTO-892	t. Other

SPECIFICATION		MESSAGE
a. Page Missing		PTO-1449: Please either initial or line through citations. (Copies provided for reference)
b. Text Continuity		
c. Holes through Data		
d. Other Missing Text		
e. Illegible Text		
f. Duplicate Text		
g. Brief Description		
h. Sequence Listing		
i. Appendix		
j. Amendments		
k. Other		
CLAIMS		
a. Claim(s) Missing		Thank you
b. Improper Dependency		
c. Duplicate Numbers		
d. Incorrect Numbering		
e. Index Disagrees		initials <i>BR</i>
f. Punctuation		RESPONSE
g. Amendments		
h. Bracketing		
i. Missing Text		
j. Duplicate Text		
k. Other		
		initials

MAR 22 2004  
PATENT & TRADEMARK OFFICE

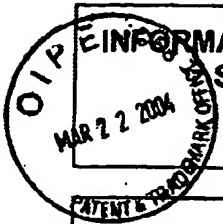
Sheet 1 of 2

<b>INFORMATION DISCLOSURE STATEMENT</b>	Atty Docket:	62604
	Serial No.:	10/603,621
	Applicant:	MEARS
	Filing Date:	AUGUST 22, 2003
	Group:	2812

U.S. PATENT DOCUMENTS							
Examiner Initials		Document Number	Date	Name	Class	Sub Class	Filing Date
	AA	4,594,603	06/10/86	Holonyak, Jr.	357	16	01/24/85
	AB	4,937,204	06/26/90	Ishibashi et al.	437	110	01/4/89
	AC	4,969,031	11/06/90	Kobayashi et al.	357	63	02/3/83
	AD	5,05,887	10/08/91	Yamazaki	357	4	01/18/90
	AE	5,216,262	06/1/93	Tsu	257	17	03/2/92
	AF	5,357,119	10/18/94	Wang et al.	257	18	02/19/93
	AG	5,684,817	11/04/97	Houdre et al.	372	45	05/1/96
	AH	5,683,934	11/4/03	Candelaria	437	134	05/3/96
	AI	5,994,164	11/30/99	Fonash et al.	438	97	03/18/98
	AJ	6,058,127	05/2/00	Joannopoulos et al.	372	92	12/12/97
	AK	6,274,007	08/14/01	Smirnov et al.	204	192	03/14/00
	AL	6,281,518	08/28/01	Sato	257	13	12/3/98
	AM	6,281,532	08/28/01	Doyle et al.	257	288	06/28/99
	AN	6,344,271	02/05/02	Yadav et al.	428	402	03/23/99
	AO	6,472,685	10/29/02	Takagi	257	77	12/2/98
	AP	6,498,359	12/24/02	Schmidt et al.	257	190	05/18/01
	AQ	2003/0034529	02/20/03	Fitzgerald et al.	257	369	10/8/02
	AR	2003/0057416	03/27/03	Currie et al.	257	19	09/20/02
FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Sub Class	Translation
	AS	02/103767	12/27/02	WO	H01L	21/20	
	AT	2,347,520	09/06/00	GB	G02B	5/18	
	AU						

<b>EXAMINER:</b>	<b>DATE CONSIDERED:</b>
<p>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</p>	

Sheet 2 of 2



<b>INFORMATION DISCLOSURE STATEMENT</b>	Atty Docket: 62604 Serial No.: 10/603,621 Applicant: MEARS Filing Date: AUGUST 22, 2003 Group: 2812
---	---

**OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)**

	AV	Xuan Luo et al.; "Chemical Design of Direct-Gap Light-Emitting Silicon", published July 25, 2002 by The American Physical Society; Vol. 89, Number 7
	AW	R. Tsu; University of North Carolina at Charlotte, "Phenomena in Silicon Nanostructure Devices"; published 09/06/2000 © Springer-Verlag 2000
	AX	P.D. Ye et al., "GaAs MOSFET with Oxide Gate Dielectric Grown by Atomic Layer Deposition"; © 2003 Agere Systems, March 2003
	AY	Novikov et al.; "Silicon-based Optoelectronics" © 1999-2003 by John Wiley & Sons, Inc.; pp/ 1-6
	AZ	
	BA	
	BB	
	BC	
	BD	
	BE	
	BF	
	BG	
	BH	
	BI	
	BJ	
	BK	
	BL	
	BM	
	BN	
	BO	
	BP	
	BQ	
	BR	
	BS	

<b>EXAMINER:</b>	<b>DATE CONSIDERED:</b>
<b>*EXAMINER:</b> Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	